



#### N-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C		
60V	7.5Ω @ V <sub>GS</sub> = 5V	210mA		

### **Description**

This MOSFET has been designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Applications**

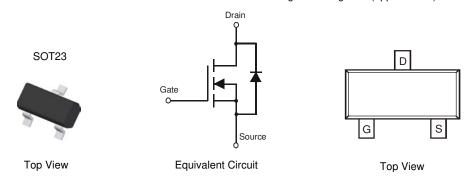
- Motor Control
- Power Management Functions

## **Features**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- · Fast Switching Speed
- Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Notes 3 & 4)
- Qualified to AEC-Q101 standards for High Reliability

#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 63
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)



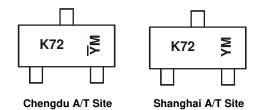
#### Ordering Information (Note 5)

Part Number	Compliance	Case	Packaging
2N7002-7-F	Standard	SOT23	3,000/Tape & Reel
2N7002-13-F	Standard	SOT23	10,000/Tape & Reel
2N7002Q-7-F	Automotive	SOT23	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Product manufactured with Date Code V12 (week 50, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V12 are built with Non-Green Molding Compound and may contain Halogens or Sb<sub>2</sub>O<sub>3</sub> Fire Retardants.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



K72 = Product Type Marking Code
VM = Date Code Marking for SAT

YM = Date Code Marking for SAT (Shanghai Assembly/ Test site)
YM = Date Code Marking for CAT (Chengdu Assembly/ Test site)

Y or  $\overline{Y}$  = Year (ex: A = 2013) M = Month (ex: 9 = September)

Date Code Kev

Date Code IV	Су															
Year	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015	2016	2017
Code	N	Р	R	S	Т	U	V	W	Χ	Υ	Z	Α	В	С	D	E
Month	Jan	F	eb	Mar	Apr	M	lay	Jun	Jul	A	ug	Sep	Oct	No	ov	Dec
Code	1		2	3	4		5	6	7		8	9	0	1	V	D



## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Drain-Source Voltage			V <sub>DSS</sub>	60	V
Drain-Gate Voltage R <sub>GS</sub> ≤ 1.0MΩ			$V_{DGR}$	60	V
Gate-Source Voltage		Continuous Pulsed	V <sub>GSS</sub>	±20 ±40	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	Steady State	$T_A = +25$ °C $T_A = +85$ °C $T_A = +100$ °C	I <sub>D</sub>	170 120 105	mA
Continuous Drain Current (Note 7) V <sub>GS</sub> = 10V	Steady State	$T_A = +25$ °C $T_A = +85$ °C $T_A = +100$ °C	I <sub>D</sub>	210 150 135	mA
Maximum Body Diode Forward Current (Note 7)		oulsed ntinuous	I <sub>S</sub>	0.5 2	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I <sub>DM</sub>	800	mA		

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Total Power Dissipation	(Note 6)	D-	370	mW	
Total Fower Dissipation	(Note 7)	P <sub>D</sub>	540		
Thermal Desistance, Junction to Ambient	(Note 6)	0	348		
Thermal Resistance, Junction to Ambient	(Note 7)	R <sub>eJA</sub>	241	°C/W	
Thermal Resistance, Junction to Case	(Note 7)	R <sub>eJC</sub>	91		
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C	

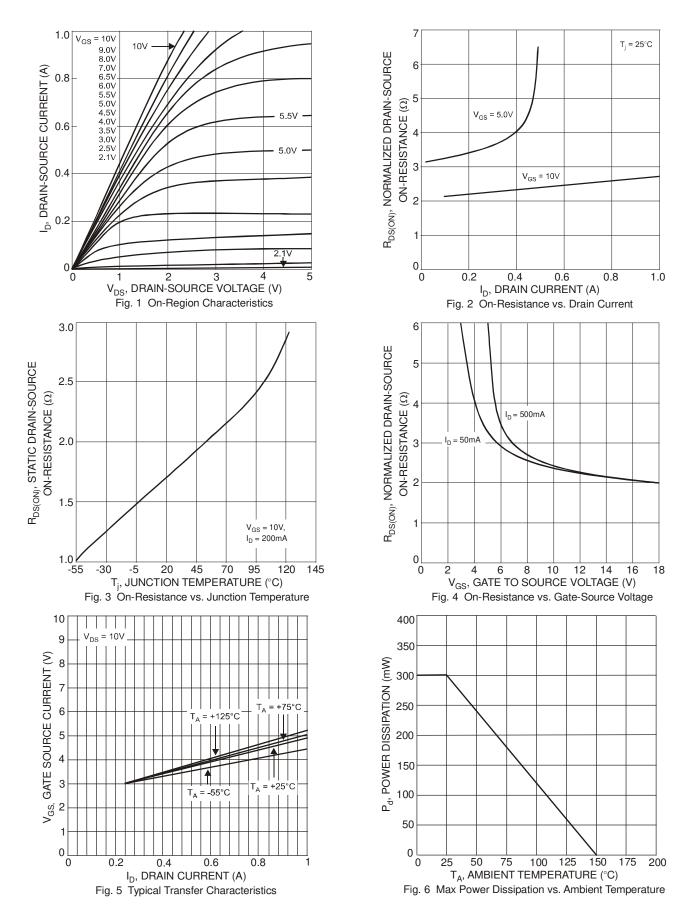
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)			J	71				
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	60	70	_	V	$V_{GS} = 0V, I_{D} = 10\mu A$	
Zero Gate Voltage Drain Current	@ T <sub>C</sub> = +25°C @ T <sub>C</sub> = +125°C	I <sub>DSS</sub>		_	1.0 500	μΑ	V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0V	
Gate-Body Leakage		I <sub>GSS</sub>		_	±10	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)								
Gate Threshold Voltage		$V_{GS(th)}$	1.0		2.5	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	@ $T_J = +25^{\circ}C$ @ $T_J = +25^{\circ}C$ @ $T_J = +125^{\circ}C$	R <sub>DS(ON)</sub>		3.2 — 4.4	7.5 5.0 13.5	Ω	$V_{GS} = 5.0V, I_D = 0.05A$ $V_{GS} = 10V, I_D = 0.5A$ $V_{GS} = 10V, I_D = 0.5A$	
On-State Drain Current		I <sub>D(ON)</sub>	0.5	1.0	_	Α	$V_{GS} = 10V, V_{DS} = 7.5V$	
Forward Transconductance		g <sub>FS</sub>	80	_	_	mS	$V_{DS} = 10V, I_D = 0.2A$	
Diode Forward Voltage		V <sub>SD</sub>	_	0.78	1.5	V	$V_{GS} = 0V, I_{S} = 115mA$	
DYNAMIC CHARACTERISTICS (Note 9)						•		
Input Capacitance		$C_{iss}$		22	50	pF	V 05V V 0V	
Output Capacitance		Coss		11	25	pF	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V f = 1.0MHz	
Reverse Transfer Capacitance		C <sub>rss</sub>		2.0	5.0	pF	1 = 1.01/11/12	
Gate resistance		$R_g$		120		Ω	$V_{DS} = 0V, V_{GS} = 0V,$ f = 1.0MHz	
Total Gate Charge (V <sub>GS</sub> = 4.5V)		$Q_g$		223	_			
Gate-Source Charge		Q <sub>gs</sub>	_	82	_	рC	$V_{DS} = 10V, I_D = 250mA$	
Gate-Drain Charge		$Q_{gd}$		178	_			
SWITCHING CHARACTERISTICS (Note 9)								
Turn-On Delay Time		t <sub>D(on)</sub>	_	2.8	_		V 20V I- 0.2A	
Turn-On Rise Time		t <sub>r</sub>	_	3.0		ns	$V_{DD} = 30V, I_D = 0.2A,$ $R_L = 150\Omega, V_{GEN} = 10V,$	
Turn-Off Delay Time		$t_{D(off)}$	_	7.6	_	$ R_{GEN} = 25\Omega$		
Turn-Off Fall Time		t <sub>f</sub>	_	5.6	_		1 IGEN - 2022	

Notes:

- 6. Device mounted on FR-4 PCB, with minimum recommended pad layout
  7. Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
  8. Short duration pulse test used to minimize self-heating effect.
  9. Guaranteed by design. Not subject to product testing.

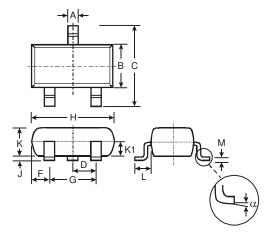






## **Package Outline Dimensions**

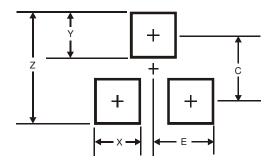
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.903	1.10	1.00				
K1	-	-	0.400				
L	0.45	0.61	0.55				
M	0.085	0.18	0.11				
α	0°	8°	-				
All Dimensions in mm							

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Υ	0.9
С	2.0
Е	1.35



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